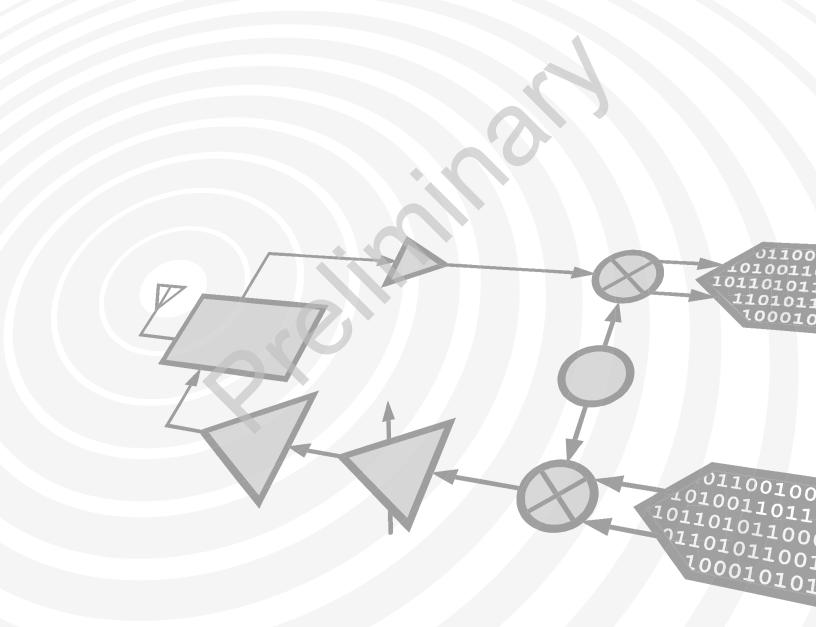




Analog Devices Welcomes Hittite Microwave Corporation



THIS PAGE INTENTIONALLY LEFT BLANK



HMC939ALP4/939ALP4E

v00.1115

1.0 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 33 GHz

Typical Applications

The HMC939ALP4 / HMC939ALP4E is ideal for:

- Fiber Optics & Broadband Telecom
- Microwave Radio & VSAT
- Military Radios, Radar & ECM
- Space Applications
- Sensors
- Test & Measurement Equipment

Features

1.0 dB LSB Steps to 31 dB

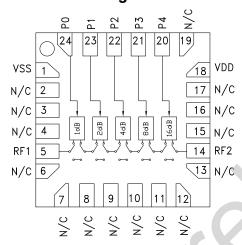
Single Positive Control Line Per Bit

±1.0 dB Typical Bit Error

High Input IP3: +43 dBm

16mm² Leadless SMT Plastic Package

Functional Diagram



General Description

The HMC939ALP4 & HMC939ALP4E are broadband 5-bit GaAs IC digital attenuators in low cost leadless surface mount packages. Covering 0.1 to 33.0 GHz, the insertion loss is less than 5 dB typical. The attenuator bit values are 1.0 (LSB), 2, 4, 8, 16 for a total attenuation of 31 dB. Attenuation accuracy is excellent at ± 0.4 dB typical step error with an IIP3 of ± 4.4 dBm. Five control voltage inputs, toggled between ± 5.4 and 0V, are used to select each attenuation state.

Electrical Specifications, $T_A = +25^{\circ}$ C, With Vdd = +5V, Vss = -5V, P0 - P4 = 0/ +5V

Parameter		Frequency (GHz)	Min.	Тур.	Max.	Units
Insertion Loss		0.1 - 18.0 GHz 18.0 - 26.5 GHz 26.5 - 33.0 GHz		4.0 5.5 6.5	5.5 7.0 8.5	dB dB dB
Attenuation Range		0.1 - 33.0 GHz		31		dB
Return Loss (RF1 & RF2, All Atten. States)		0.1 - 33.0 GHz		12		dB
16 -	- 15 dB States - 31 dB States - 31 dB States	0.1 - 33.0 GHz 0.1 - 20.0 GHz 20.0 - 33.0 GHz	± (0.5 + 5%) of Atten. Setting Max ± (0.5 + 5%) of Atten. Setting Max ± (0.6 + 8%) of Atten. Setting Max		dB dB dB	
Input Power for 0.1 dB Compression		0.1 - 0.5 GHz 0.5 - 33.0 GHz		20 25		dBm dBm
Input Third Order Intercept Point (Two-Tone Input Power= 0 dBm Each Tone)		0.1 - 0.5 GHz 0.5 - 33.0 GHz		40 43		dBm dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON/tOFF (50% CTL to 10/90% RF)		0.1 - 33.0 GHz		60 90		ns ns
Idd		0.1 - 33.0 GHz	2.5	4.5	6.5	mA
Iss		0.1 - 33.0 GHz	-7.0	-5.0	-3.0	mA



v00.1115

1.0 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 33 GHz

Absolute Maximum Ratings

RF Input Power (0.1 to 33.0 GHz)	+25 dBm
Control Voltage (P0 to P4)	Vdd + 0.5V
Vdd	+7 Vdc
Vss	-7 Vdc
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 6.8 mW/°C above 85 °C)	0.451 W
Thermal Resistance	144 °C/W
Storage Temperature	-65 to + 150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A



Bias Voltages & Currents

Vdd	+5V @ 4.5 mA		
Vss	-5V @ 5 mA		

Control Voltage

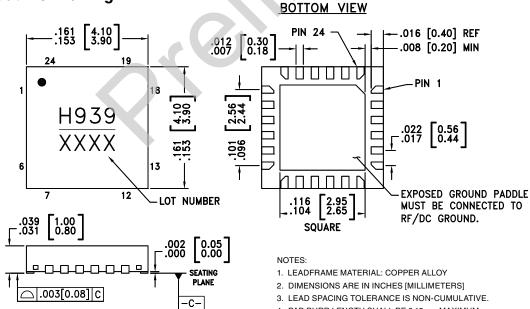
State	Bias Condition
Low	0 to 0.8V @ 1 μA
High	2 to 5V @ 1 μA

Truth Table

Control Voltage Input					Attenuation	
P4 16 dB	P3 8 dB	P2 4 dB	P1 2 dB	P0 1 dB	State RF1 - RF2	
High	High	High	High	High	Reference I.L.	
High	High	High	High	Low	1 dB	
High	High	High	Low	High	2 dB	
High	High	Low	High	High	4 dB	
High	Low	High	High	High	8 dB	
Low	High	High	High	High	16 dB	
Low	Low	Low	Low	Low	31 dB	

Any Combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.





- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.